

Supporting Information for

Modulating 2D Heterointerface with g-C₃N₄ Meshes: A Suitable Hetero-Layered Architecture for High-Power and Long-Life Energy Storage

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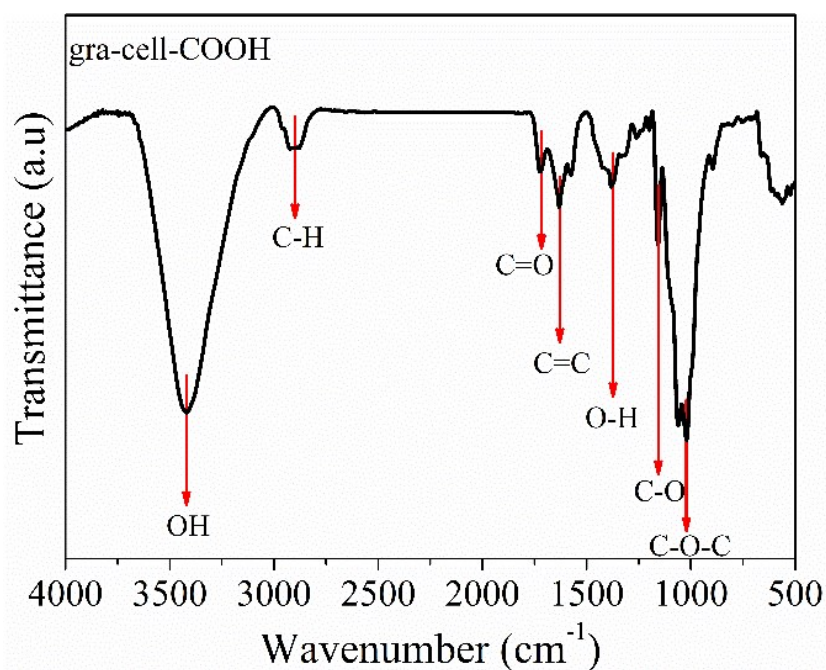


Figure S1 FTIR spectrum of gra-cell-COOH. The absorbance peaks at 1021, 1167, 1387, 2900 and 3435 cm^{-1} stem from celluloses, corresponding to the C–O–C pyranose ring skeletal vibration, C–O antisymmetric stretching vibration in ester, O–H deformation, H–O–H bending of the absorbed water, aliphatic C–H stretching vibrations and stretching of –OH, respectively.

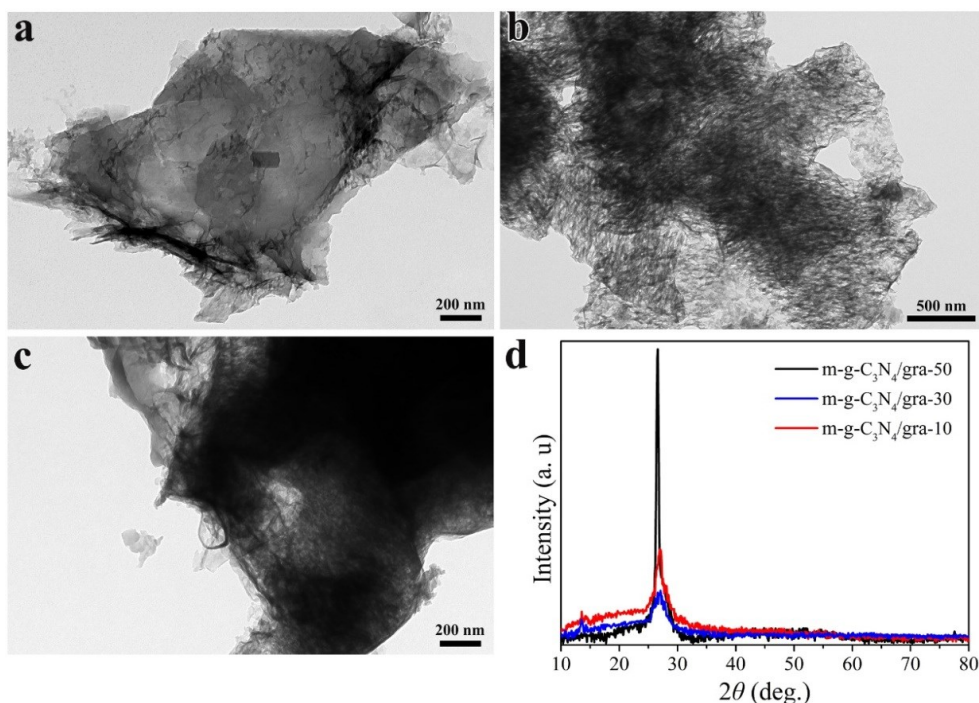


Figure S2 TEM images of (a) m-g-C₃N₄/gra-50, (b) m-g-C₃N₄-30 and (c) m-g-C₃N₄-10; (d) XRD patterns of m-g-C₃N₄/gra-50, m-g-C₃N₄-30 and m-g-C₃N₄-10.

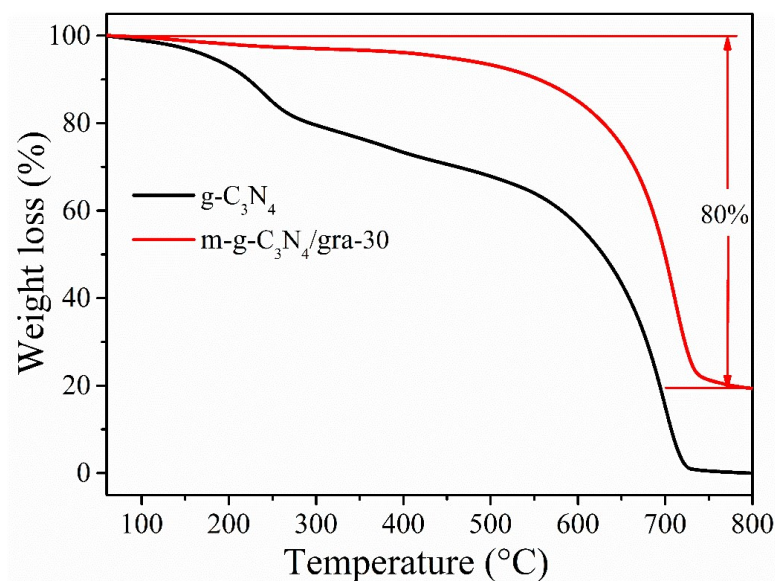


Figure S3 TG curves of g-C₃N₄ and m-g-C₃N₄/gra-30 samples tested under N₂ atmosphere. The g-C₃N₄ decomposed completely at temperatures up to 800 °C while the weight of graphene kept constant under the same condition¹. The residual mass ratio in the m-g-C₃N₄/gra-30 composites at 800°C is related to the weight ratio of graphene in the composites. Hence, the weight ratio of graphene in m-g-C₃N₄/gra-30 composites is ~20%.

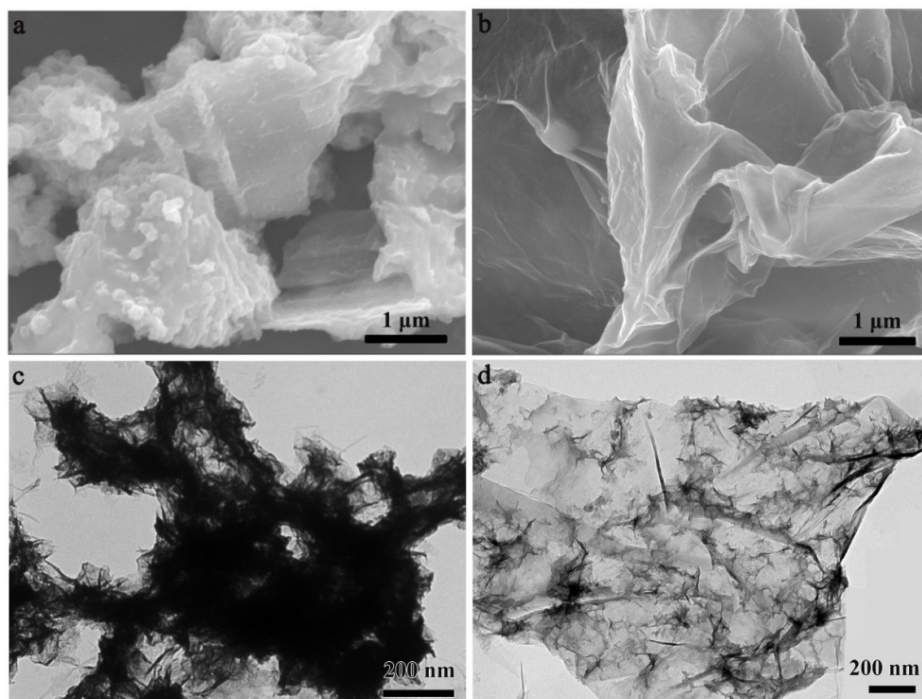
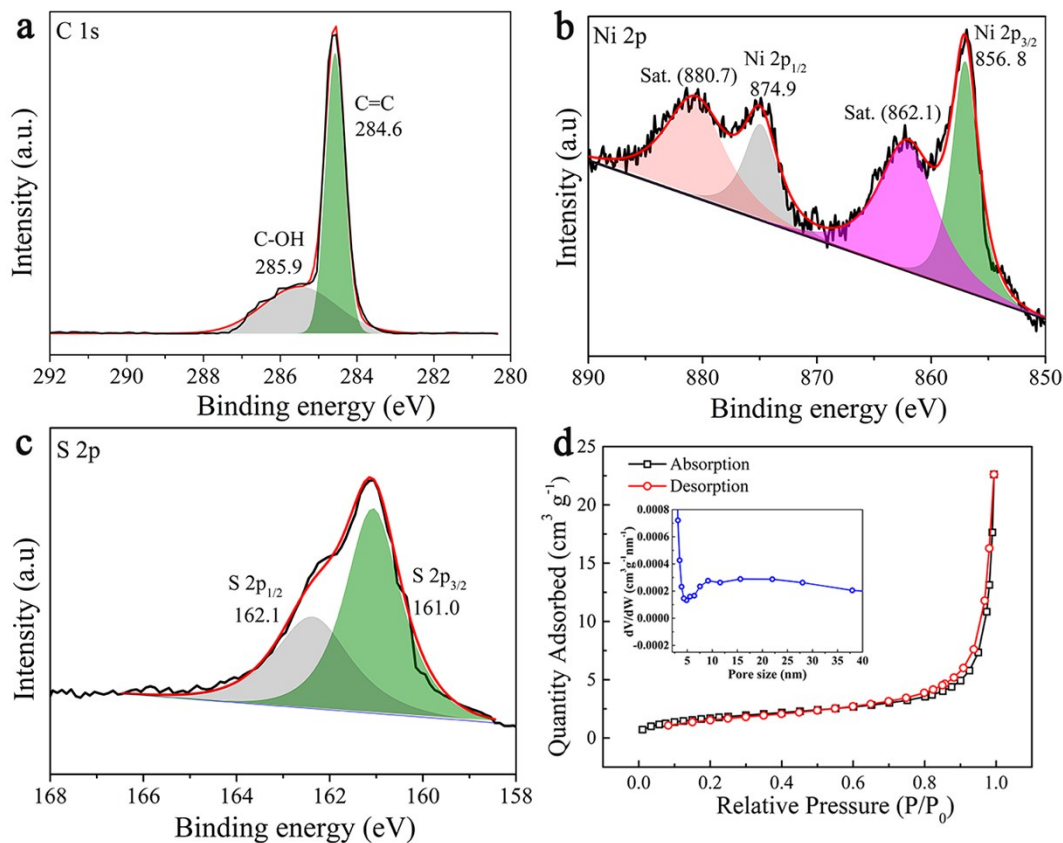


Figure S4 SEM images of (a) pure NiS₂ and (b) NiS₂/gra, TEM image of (c) pure NiS₂ and (d) NiS₂/gra.



Fig

ure S5 XPS spectra of C 1s (a), Ni 2p (b) and S 2p (c) in NiS₂/gra, N₂ adsorption-desorption isotherms (d) of NiS₂/gra (inset: pore-size distribution).

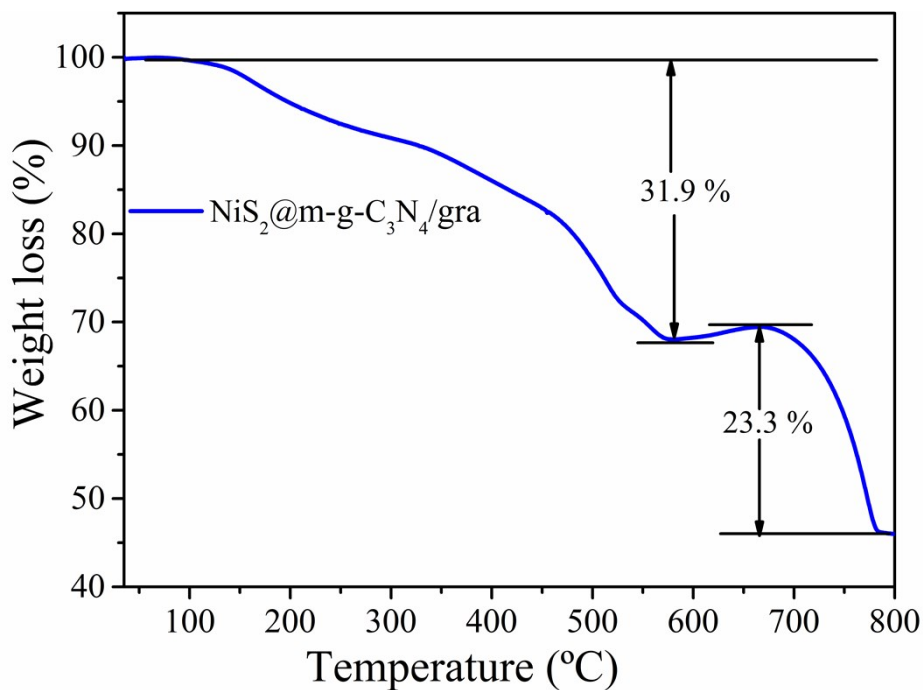
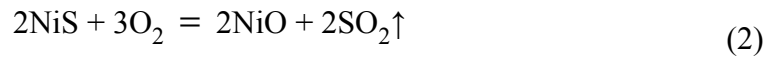
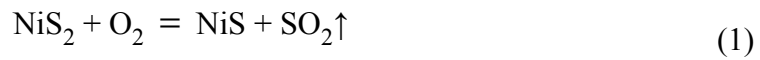


Figure S6 TG curve of NiS₂@m-g-C₃N₄/gra tested under air condition.

To evaluate the content of NiS₂ component in the NiS₂@m-g-C₃N₄/gra, TG analysis is carried out in air atmosphere. A major weight loss of 31.9 wt.% below 580 °C is due to the burning of m-g-C₃N₄/gra and decomposition of NiS₂ to NiS². Subsequently, the weight was faintly increased within the temperature range from 580 °C to 680 °C stage, which might be ascribed to the transformation of NiS to NiSO₄³. The final mass loss of 23.3 wt.% within the range of 680-780 °C could be ascribed to the decomposition of NiSO₄ to NiO. Based on these results, the reactions of NiS₂ and O₂ during calcination can be proposed as following:



Therefore, the content of NiS₂ component can be calculated from the residual mass after heating the NiS₂@m-g-C₃N₄/gra composites above 780°C, which is close to 75.7 wt.%.

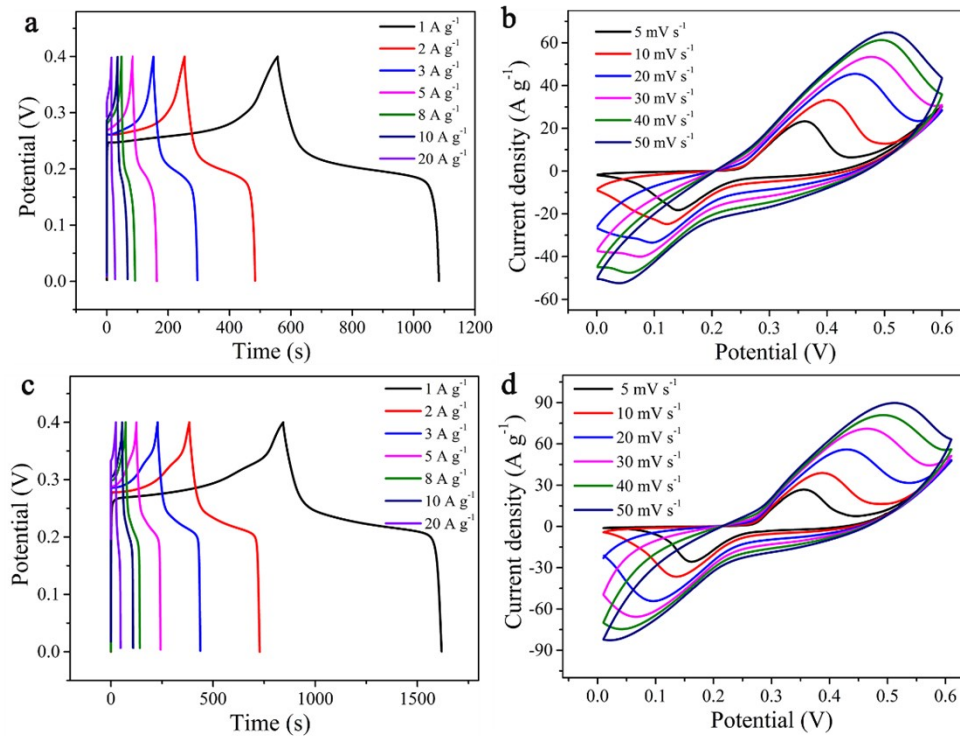


Figure S7 GCD curves of (a) pure NiS₂ and (c) NiS₂/gra electrode; CV curves of (b) pure NiS₂ and (d) NiS₂/gra electrode.

and (d) NiS₂/gra electrode.

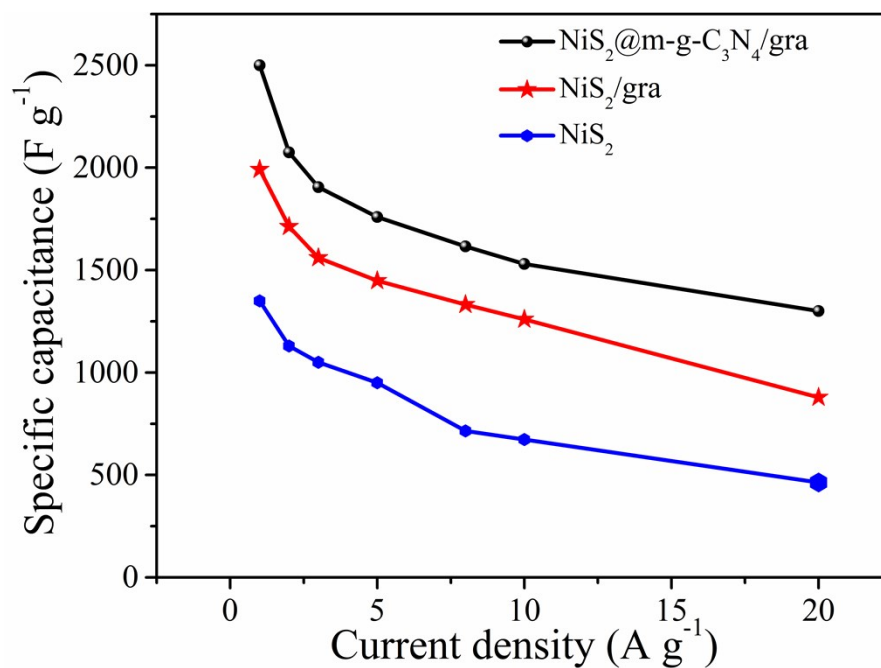


Figure S8 Comparison of specific capacitance of three electrodes at current densities from 1 to 20 A g⁻¹.

Table S1 The specific capacity/capacitance of the NiS₂, NiS₂/gra and NiS₂@m-g-C₃N₄/gra electrodes at various current densities (A g⁻¹).

Current density (A g ⁻¹)	Specific capacity (mAh g ⁻¹) / capacitance (F g ⁻¹)		
	NiS ₂ @m-g-C ₃ N ₄ /gra	NiS ₂ /gra	NiS ₂
1	296 / 2500	234 / 1991	154 / 1350
2	244 / 2075	208 / 1712	132 / 1130
3	234 / 1905	190 / 1560	121 / 1050
5	200 / 1759	175 / 1448	105 / 950
8	176 / 1616	159 / 1332	86 / 715
10	164 / 1530	149 / 1260	78 / 673
20	150 / 1300	112 / 878	45 / 463

Table S2 Comparison of electrochemical performance of recently reported TMDs/graphene heterostructured electrodes for SC applications.

Electrode	Specific capacitance/capacity	Electrolyte	Ref.
α -NiS/rGO	744 C g ⁻¹ (1 A g ⁻¹)	2 M KOH	4
ANM-NiS-rGO	150 mAh g ⁻¹ (1 A g ⁻¹)	3 M KOH	5
VS ₄ /rGO/CoS ₂ @Co	274.3 mAh g ⁻¹ (0.625 A g ⁻¹)	2 M KOH	6
0.5 cP/rGO/Co ₉ S ₈	788.9 (1 A g ⁻¹)	2M KOH	7
Ni ₃ S ₄ @rGO-20	1830 (2 A g ⁻¹)	2 M KOH	8
MoS ₂ /3D graphene	102.46 (0.5 A g ⁻¹)	1 M KOH	9
MoS ₂ @3DGN	315.6 (1 A g ⁻¹)	3 M KOH	10
MnS@rGO/Ni-foam	2220 (0.5 A g ⁻¹)	3 M KOH	11
NiS ₂ @m-g-C ₃ N ₄ /gra	296 mAh g ⁻¹ /2500 F g ⁻¹ (1 A g ⁻¹)	2 M KOH	This work

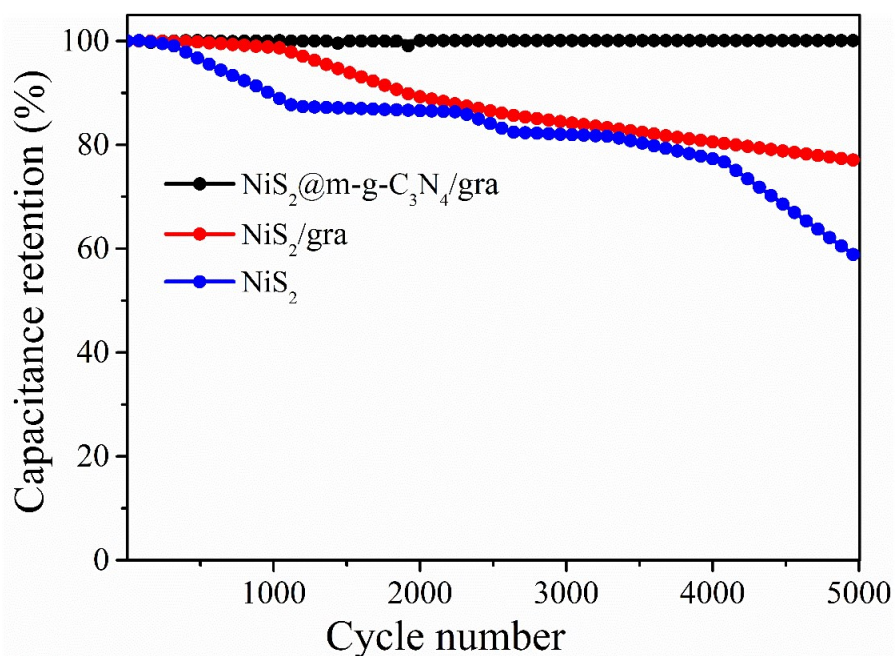


Figure S9 Cycle performances of NiS₂@m-g-C₃N₄/gra, NiS₂/gra and NiS₂ electrodes tested at 5 A g⁻¹.

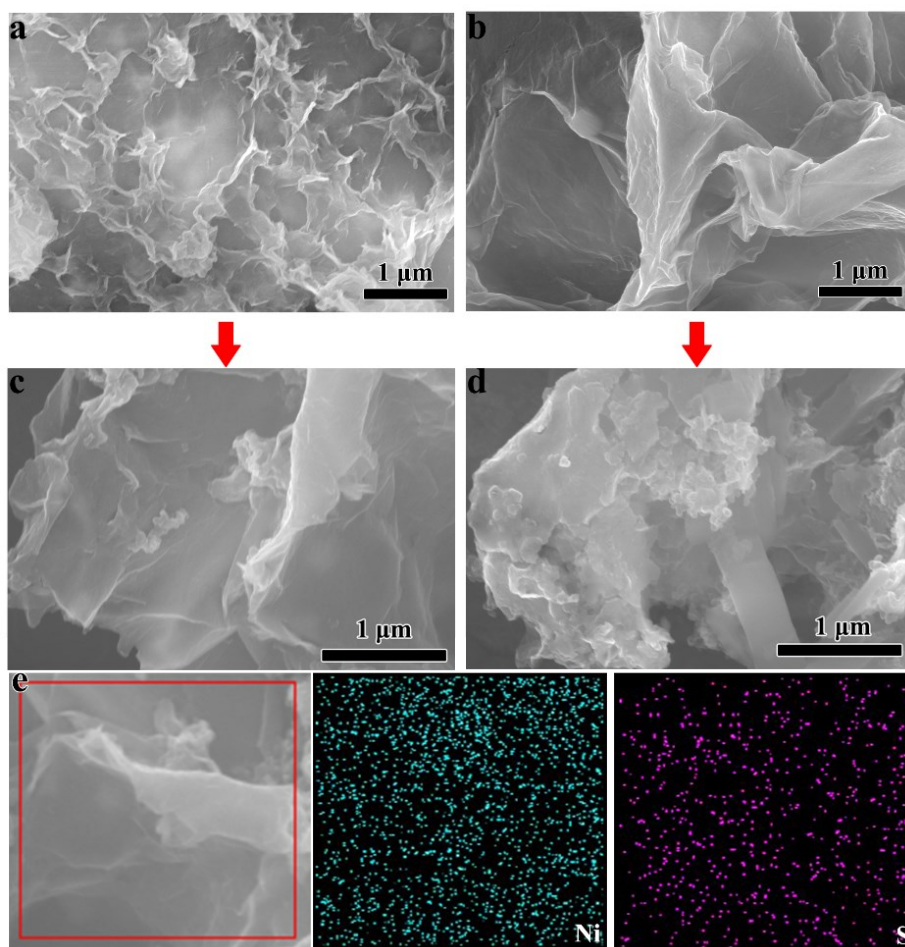


Figure S10 SEM pictures of NiS₂@m-g-C₃N₄/gra electrode before (a) and after cycling test (c), SEM pictures of NiS₂/gra electrode before (b) and after cycling test (d), (e) elemental mapping characterizations for Ni and S of NiS₂@m-g-C₃N₄/gra after cycling.

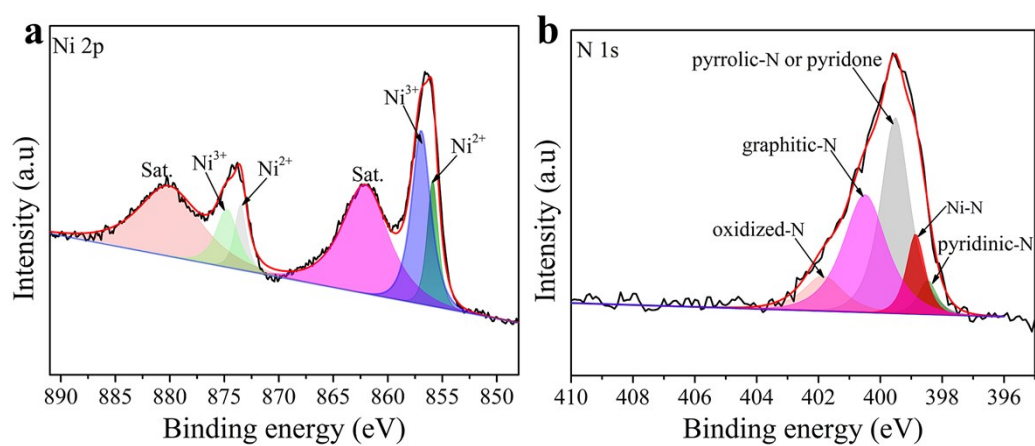


Figure S11 XPS spectrum of Ni 2p (a) and N 1s (b) of NiS₂@m-g-C₃N₄/gra hybrids after cycling test.

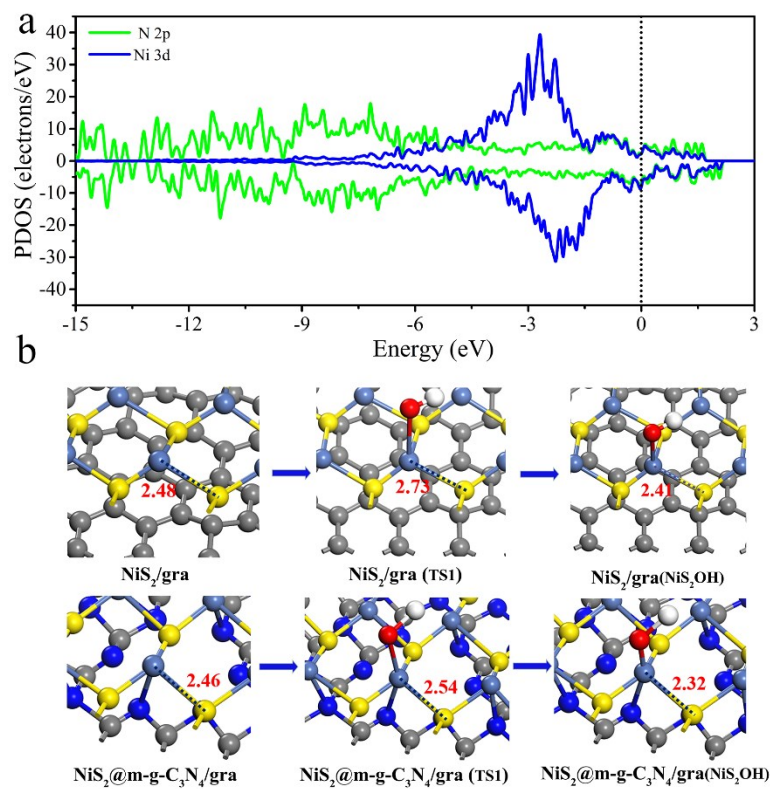


Figure S12 (a) Partial density of states per eV for the nitrogen 2p orbital and nickel 3d orbital in NiS₂@m-g-C₃N₄/gra, and change in Ni-S bond length (b) of NiS₂@m-g-C₃N₄/gra and NiS₂/gra during electrochemical reaction.

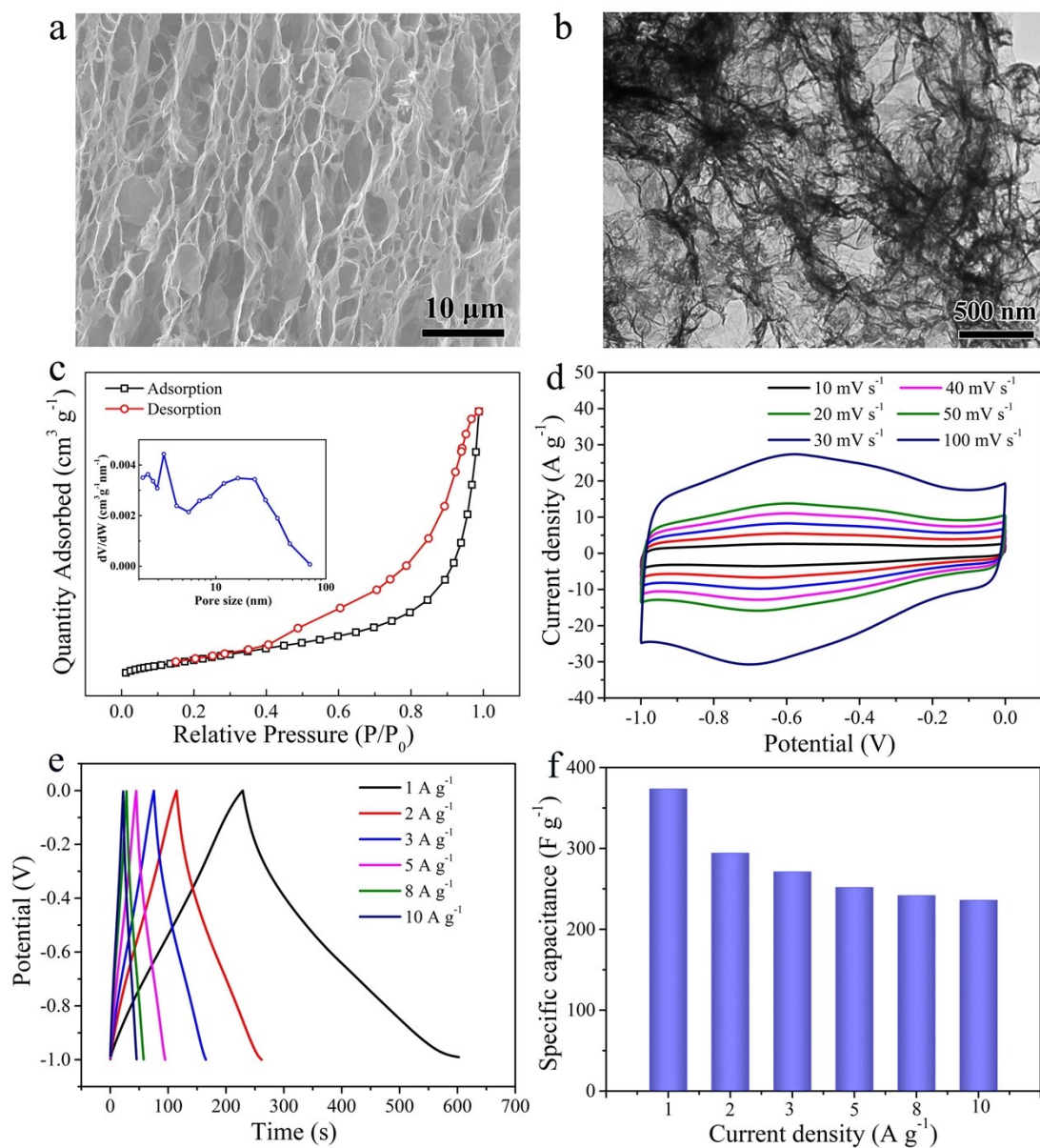


Figure S13 SEM image (a) and TEM image (b) of g-C₃N₄/RGO, N₂ adsorption-desorption isotherms (c) of g-C₃N₄/RGO (inset: pore-size distribution), electrochemical performance of CV curves (d) and GCD curves (e) of g-C₃N₄/RGO, the specific capacitances (f) of g-C₃N₄/RGO at different current densities.

Table S3 Performance comparison of NiS₂@m-g-C₃N₄/gra//RGO/g-C₃N₄ and

various HSC devices based on heterostructured hybrids as cathode

Devices	Energy density (Wh kg ⁻¹)	Power density (W kg ⁻¹)	Cycle life and capacitance retention	Ref.
0.5 cP/rGO/Co ₉ S ₈ //AC	50.3	415.8	8000 cycles (96%)	7
Ni ₃ S ₄ @rGO-20//RGO	37.3	398	10000 cycles (91.4%)	8
MoS ₂ @3DGN //AC	36.43	400	4000 cycles (100%)	10
NiS ₂ @MoS ₂ //AC	37.2	800	10000 cycles (80.5%)	12
NiMn ₂ O ₄ @CoS//SCG	44.56	700	5000 cycles (94.0%)	13
MoS ₂ /NiS //AC	38.6	400	10000 cycles (100%)	14
NiS ₂ @m-g-C ₃ N ₄ /gra //RGO/g-C ₃ N ₄	63.0	931.2	10000 cycles (100%)	This work

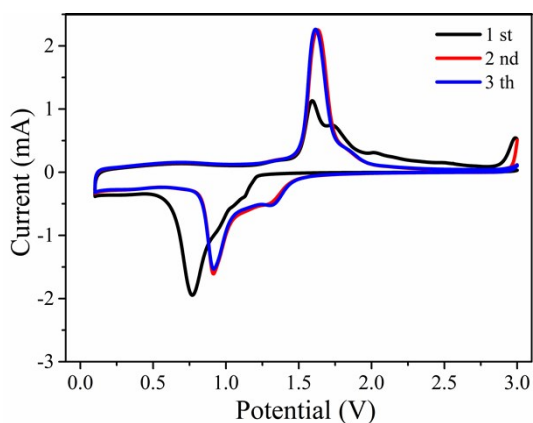


Figure S14 CV curves the NiS₂@m-g-C₃N₄/gra electrode at a scan rate of 0.5 mV s⁻¹ with a voltage range of 0.1-3.0 V versus Na⁺/Na.

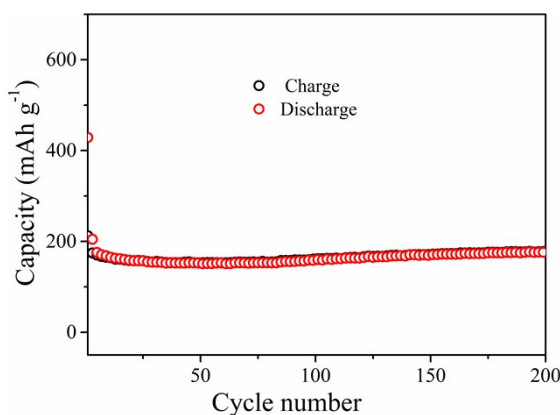


Figure S15 Cycling performance of m-g-C₃N₄/gra at a current density of 0.1 A g⁻¹.

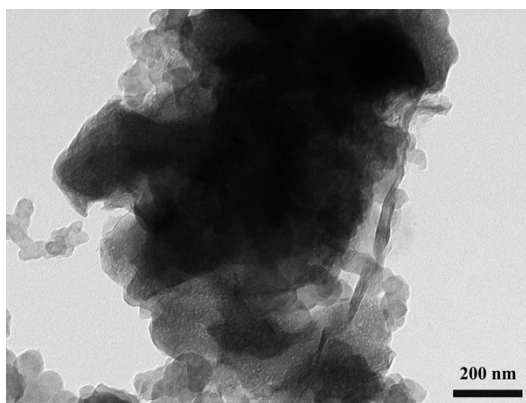


Figure S16 TEM image of NiS₂@m-g-C₃N₄/gra electrode after SIBs test at 2 A g⁻¹ for 100 cycles.

References

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